

4 A - Triac in IPAK package



Features

- 4 A Triac
- V_{DRM} / V_{RRM} = 600 V and V_{DSM} / V_{RSM} = 750 V
- 125 °C maximum junction temperature T_j
- IPAK package
- 4 quadrants triacs with I_{GT} = 3 mA
- · Halogen-free molding, lead-free plating
- ECOPACK2 compliant

Applications

- Actuators
 - Heating elements
 - Inrush current limiting circuits

Product status link

Z0402MH

Description

The Z0402MH series is 4 A Triac housed in compact through-hole IPAK package. This 4 quadrants device is suited to home appliances or power tools and industrial systems and drives loads up to 4 A.



1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter			Unit	
I _{T(RMS)}	RMS on-state current (full sine wave)	T _c = 107 °C	4	Α	
l	Non repetitive surge peak on-state current (full cycle,	t = 16.7 ms	16	^	
I _{TSM}	T _j initial = 25 °C)	t = 20 ms	15	Α	
l ² t	I ² t value for fusing	t _p = 10 ms	1.5	A ² s	
dl/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$, tr ≤ 100 ns, f = 120 Hz		50	A/µs	
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage	ve peak off-state voltage T_j = 125 °C		V	
V _{DSM} /V _{RSM}	Non Repetitive peak off-state voltage, 10 ms	750	V		
I _{GM}	Maximum peak gate current	t = 20 up T = 125 °C	1.2	Α	
P _{GM}	Maximum gate power dissipation	t_p = 20 μ s, T_j = 125 °C t_p = 20 t_p = 125 °C		W	
T _{stg}	Storage temperature range	-40 to +125	°C		
Tj	Operating junction temperature range	-40 to +125	°C		
TL	Maximum lead temperature for soldering during 10 s	260	°C		

Table 2. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Test conditions	Value	Unit		
I _{GT} ⁽¹⁾	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Max.	3	mA
V _{GT}	V _D = 12 V, R _L = 33 Ω		Max.	1.3	V
V _{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$ $T_j = 125 \text{ °C}$		Min.	0.2	V
IL	I _G = 1.2 x I _{GT}	I-III-IV	Max.	10	mA
'L	IG - 1.2 × IG	II	Max.	15	mA
I _H ⁽²⁾	I _T = 500 mA, gate open		Max.	5	mA
dV/dt (2)	V_D = 67 % V_{DRM} ; V_R = 67 % V_{RRM} , gate open	T _j = 110 °C	Min.	20	V/µs
(dV/dt)c (2)	$(dI/dt)c = 1.8 \text{ A/ms}$ $T_j = 110 ^{\circ}\text{C}$		Min.	0.5	V/µs

^{1.} For both polarities of OUT pin referenced to COM pin.

Table 3. Static characteristics

Symbol	Test conditions	Tj		Value	Unit
V _{TM} ⁽¹⁾	$I_{TM} = 5.5 \text{ A}, t_p = 380 \mu\text{s}$	25 °C	Max.	2	V
V _{TO} ⁽¹⁾	Threshold voltage	125 °C	Max.	0.95	V
R _D ⁽¹⁾	Dynamic resistance	125 °C	Max.	180	mΩ
I _{DRM} /I _{RRM}	$V_D = V_R = V_{DRM} = V_{RRM}$	25 °C	Max.	5	μΑ
		125°C		0.5	mA

^{1.} For both polarities of A2 referenced to A1.

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^{2.} For both polarities of A2 referenced to A1.



Table 4. Thermal resistance

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case	Max.	3	°C/W
R _{th(j-a)}	Junction to ambient	Тур.	70	°C/W

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1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)

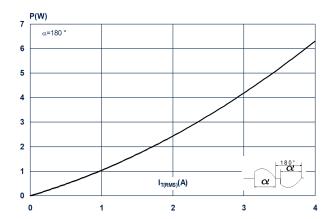


Figure 2. Average and DC on-state current versus case temperature

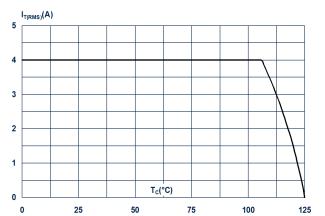


Figure 3. On-state RMS current versus ambient temperature (full cycle)

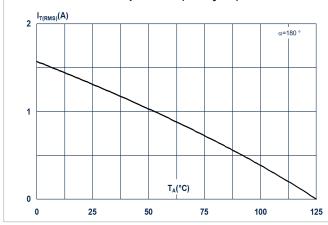


Figure 4. Relative variation of thermal impedance versus pulse duration

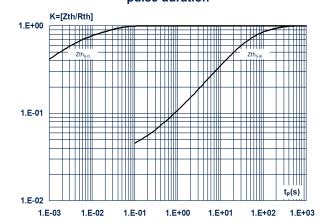


Figure 5. Relative variation of gate triggering current and voltage versus junction temperature (typical values)

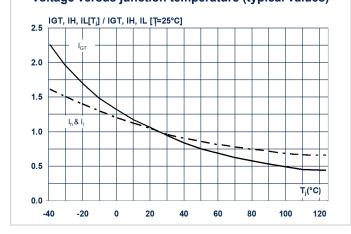
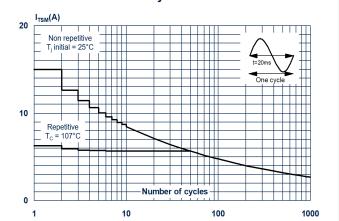


Figure 6. Surge peak on-state current versus number of cycles



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Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_{\rm p}$ < 10 ms and corresponding value of l^2t

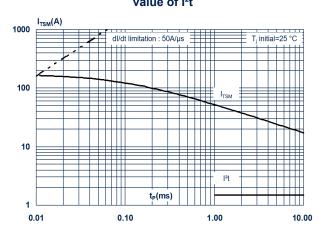


Figure 8. On-state characteristics (maximum values)

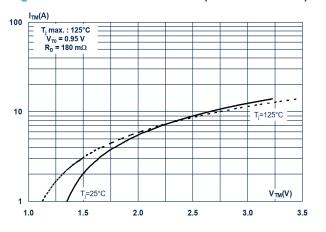


Figure 9. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)

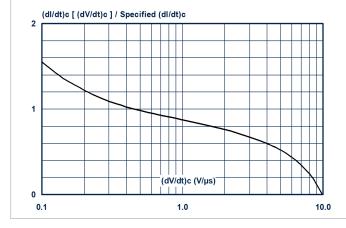


Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

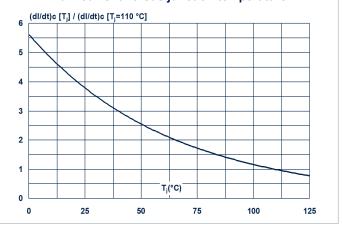
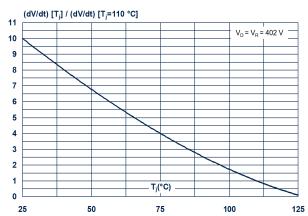


Figure 11. Relative variation of static dV/dt immunity versus junction temperature



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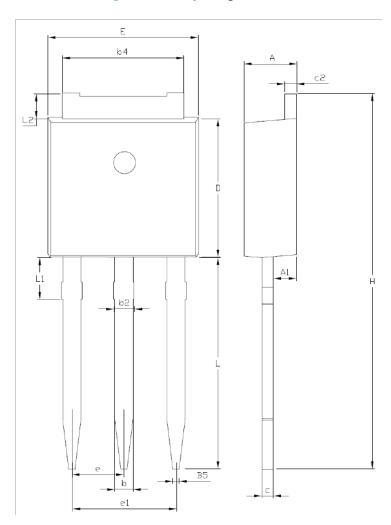
Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 IPAK package information

- Molding compouned resin is halogen free and meets UL94 flammability standard, level V0
- · Lead-free package leads plating

Figure 12. IPAK package outline



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Table 5. IPAK package mechanical data

	Dimensions					
Ref.	MillimetersInches (for reference only)					
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	2.20		2.40	0.086		0.094
A1	0.90		1.10			0.035
b	0.64		0.90	0.025		0.035
b2			0.95			0.037
b4	5.20		5.43			
B5		0.30			0.012	
С	0.45		0.60			
c2	0.46		0.60			
D	6		6.20			
E	6.40		6.65	0.252		0.262
е		2.28			0.090	
e1	4.40		4.60	0.173		0.181
Н		16.10			0.634	
L	9		9.60	0.354		0.377
L1	0.8		1.20	0.031		0.047
L2		0.80	1.25		0.031	0.049
V1		10°			10°	

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3 Ordering information

Figure 13. Ordering information scheme

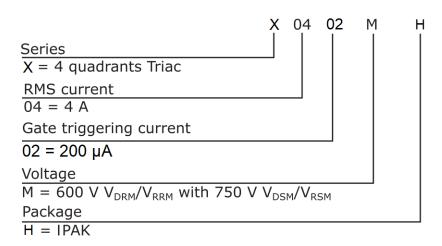


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
Z0402MH	Z0402MH	IPAK	0.3 g	75	Tube

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Revision history

Table 7. Document revision history

Date	Revision	Changes
06-Sep-2022	1	Initial release.

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